

SPICE PARAMETER
RB496EA

Characteristic of inner diode

No.	NAME	PARAMETER	UNIT	DATA	
1	IS	Saturation Current	A	1.490E-05	
2	N	Emission Coefficient	-	1.046	
3	RS	Series Resistance	Ω	0.080	
4	IKF	High-injection Knee Current	A	45.160	
5	XTI	Temperature Exponent at IS	-	2	
6	EG	Autivation Energy	eV	0.69	default
7	CJO	Junction Capacitance	F	2.700E-10	
8	M	Granding Coefficient	-	0.509	
9	VJ	Junction Potential	V	0.320	
10	FC	Depletion Capacitance Coefficient	-	0.5	default
11	BV	Breakdown Voltage	V	20	
12	IBV	Breakdown Current	A	1.000E-04	
13	TT	Transit Time	SEC	2.220E-08	